NSN 5962-01-347-8885

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View Online at https://aerobasegroup.com/nsn/5962-01-347-8885
Overall Height:
0.400 inches
Overall Width:
Between 0.290 inches and 0.320 inches
Body Length:
1.060 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
300.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
1097f330 serial input board
Features Provided:
Burn in and bipolar and monolithic and programmed and radiation hardened
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
16 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-8 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Programmed pal
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 12.0 volts power source
Memory Device Type:
Programmed
Special Features:

Item must comply with requirements of defense electronic supply center production standard no. L04430; for navy nuclear propulsion plant products only

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Test	Data	Document	ŀ
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96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 printed circuit

Shelf Life: N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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